

**Test Your fiziks concepts!****Topic: Quantum Mechanics****(For CSIR NET-JRF, GATE, JEST and TIFR Aspirants)**

**Q.** A particle is in the ground state of an infinite square well potential is given by,

$$V(x) = \begin{cases} 0 & \text{for } -a \leq x \leq a \\ \infty & \text{otherwise} \end{cases}$$

The probability to find the particle in the interval between  $-\frac{a}{2}$  and  $\frac{a}{2}$  is

- (a)  $\frac{1}{2}$                       (b)  $\frac{1}{2} + \frac{1}{\pi}$                       (c)  $\frac{1}{2} - \frac{1}{\pi}$                       (d)  $\frac{1}{\pi}$

**Ans.: (b)**

**Solution.:** The probability to find the particle in the interval between  $-\frac{a}{2}$  and  $\frac{a}{2}$  is

$$\begin{aligned} &= \int_{-a/2}^{a/2} \sqrt{\frac{2}{2a}} \cdot \sqrt{\frac{2}{2a}} \cos \frac{\pi x}{2a} \cdot \cos \frac{\pi x}{2a} dx = \int_{-a/2}^{a/2} \frac{1}{a} \cos^2 \frac{\pi x}{2a} dx = \frac{1}{a} \times \frac{1}{2} \left[ \int_{-a/2}^{a/2} \left( 1 + \cos \frac{2\pi x}{2a} \right) dx \right] \\ &= \frac{1}{2a} \left[ x + \frac{a}{\pi} \sin \frac{\pi x}{a} \right]_{-a/2}^{a/2} = \frac{1}{2a} \left[ \frac{a}{2} + \frac{a}{2} + \frac{a}{\pi} (1+1) \right] = \frac{1}{2a} \left[ a + \frac{2a}{\pi} \right] = \left( \frac{1}{2} + \frac{1}{\pi} \right) \end{aligned}$$

**Note:**

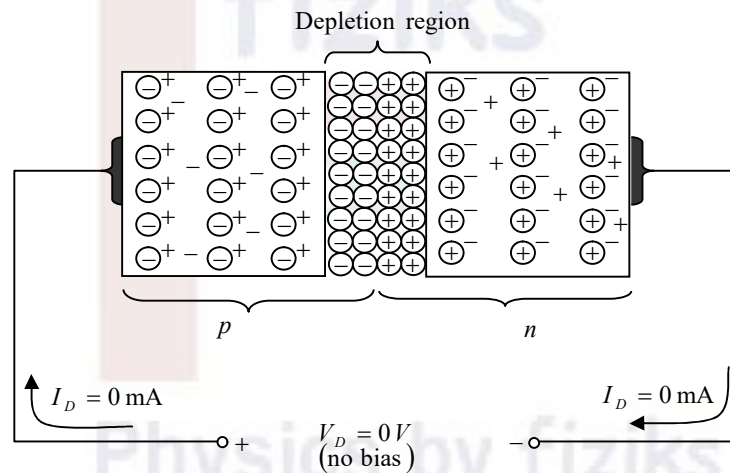
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**Test Your fiziks concepts!****Topic: Electronics****(For IIT-JAM, JEST, TIFR and CUET Aspirants)**

**Q.** In an open circuited p-n junction diode, the barrier voltage at the junction is generated due to

- (a) Minority carriers in the p and n sides
- (b) Majority carriers in the p and n sides
- (c) Immobile negative charge in the p-side and positive charge in the n-side
- (d) Immobile positive charge in the p-side and negative charge in the n-side

**JEST-2021\_Part A-1M****Ans.1: (c)****Solution.:**

**Figure:** p-n junction with no applied bias.

**Note:**

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**Test Your fiziks concepts!****Topic: Modern Physics****(For PGT: KVS, NVS, DSSSB, State Education Boards, etc.)**

**Q.** In the hydrogen atom spectrum. the ratio of the longest wavelength in the Lyman series (final state  $n = 1$ ) to that in the Balmer series (final State  $n = 2$ ) is

- (a)  $\frac{36}{5}$                       (b)  $\frac{5}{27}$                       (c)  $\frac{27}{5}$                       (d)  $\frac{4}{3}$

**Ans.: (b)**

**Solution.:** According to Bohr Theory  $\frac{1}{\lambda_L} = R \left( \frac{1}{n_f^2} - \frac{1}{n_i^2} \right)$

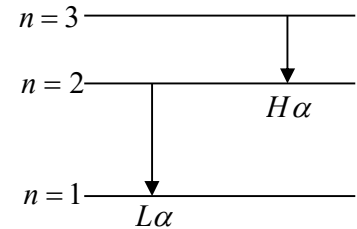
The longest wavelength in the Lyman series is

$$\Rightarrow \frac{1}{\lambda_L} = R \left( \frac{1}{1} - \frac{1}{2^2} \right) = R \left( \frac{3}{4} \right) \Rightarrow \lambda_L = \frac{4}{3R}$$

The longest wavelength in the Balmer series is

$$\Rightarrow \frac{1}{\lambda_B} = R \left( \frac{1}{2^2} - \frac{1}{3^2} \right) = R \left( \frac{1}{4} - \frac{1}{9} \right) = R \left( \frac{9-4}{36} \right) \Rightarrow \frac{1}{\lambda_B} = R \left( \frac{5}{36} \right) \Rightarrow \lambda_B = \frac{36}{5R}$$

$$\Rightarrow \frac{\lambda_L}{\lambda_B} = \frac{4}{3R} \times \frac{5R}{36} = \frac{5}{27}$$



**Note:**

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**Test Your fiziks concepts!****Topic: Quantum Mechanics****(For CSIR NET-JRF, GATE, JEST and TIFR Aspirants)**

**Q.** The wavefunction of a free particle of mass  $m$ , constrained to move in the interval  $-L \leq x \leq L$ , is  $\psi(x) = A(L+x)(L-x)$ , where  $A$  is the normalization constant. The probability

that the particle will be found to have the energy  $\frac{\pi^2 \hbar^2}{2mL^2}$  is

- (a) 0                      (b)  $\frac{1}{\sqrt{2}}$                       (c)  $\frac{1}{2\sqrt{3}}$                       (d)  $\frac{1}{\pi}$

**Ans.: (a)**

**Solution.:**  $E_n = \frac{n^2 \pi^2 \hbar^2}{8mL^2} \Rightarrow E_1 = \frac{\pi^2 \hbar^2}{8mL^2}, E_2 = \frac{4\pi^2 \hbar^2}{8mL^2} = \frac{\pi^2 \hbar^2}{2mL^2}$

$$|\phi_1\rangle = \sqrt{\frac{2}{2L}} \cos \frac{\pi x}{2L}; \quad -L \leq x \leq L \quad \text{and} \quad |\phi_2\rangle = \sqrt{\frac{2}{2L}} \sin \frac{2\pi x}{2L}; \quad -L \leq x \leq L$$

$$P(E_2) = \frac{|\langle \phi_2 | \psi \rangle|^2}{\langle \psi | \psi \rangle} = \frac{\left| \int_{-L}^L \sqrt{\frac{2}{2L}} \sin \frac{2\pi x}{2L} A(L+x)(L-x) dx \right|^2}{\int_{-L}^L A^2 (L+x)^2 (L-x)^2 dx} = 0$$

$$\int_{-L}^L \sin \frac{2\pi x}{2L} (L+x)(L-x) dx = 0 \quad \text{where, } \frac{2\pi x}{2L} (L+x)(L-x) \text{ is odd}$$

**Note:**

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**Test Your fiziks concepts!****Topic: Electronics****(For IIT-JAM, JEST, TIFR and CUET Aspirants)**

**Q.** In a  $pn$  junction, dopant concentration on the  $p$ -side is higher than that on the  $n$ -side.

Which of the following statements is not correct, when the junction is unbiased?

- (a) The width of the depletion layer is larger on the  $n$ -side.
- (b) At thermal equilibrium the Fermi energy is higher on the  $p$ -side.
- (c) In the depletion region, number of negative charges per unit area on the  $p$ -side is equal to number of positive charges per unit area on the  $n$ -side
- (d) The value of the built-in potential barrier depends on the dopant concentration.

**Ans.: (b)**

**Solution.:**

- (a) Since  $p$ -region is heavily doped and  $n$ -region is lightly doped, on  $n$ -side width of depletion layer will be more and on  $p$ -side width of the depletion layer will be less.
- (b) In an unbiased  $pn$  junction at thermal equilibrium the Fermi energy is at same level on both side.
- (c) In the depletion region, number of negative charges per unit area on the  $p$ -side is equal to number of positive charges per unit area on the  $n$ -side
- (d) The value of the built-in potential barrier depends on the dopant concentration since

$$V_0 = \frac{kT}{e} \ln \frac{N_A N_D}{n_i^2}$$

**Note:**

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**Test Your fiziks concepts!****Topic: Modern Physics****(For PGT: KVS, NVS, DSSSB, State Education Boards, etc.)**

**Q.** Let  $T_g$  and  $T_e$  be the kinetic energies of the electron in the ground and the third excited states of a hydrogen atom, respectively. According to the Bohr model, the ratio  $\frac{T_g}{T_e}$  is

(a) 3

(b) 4

(c) 9

(d) 16

**Ans.: (d)**

**Solution.:** From Bohr model the kinetic energy and Total energy  $\langle E \rangle$  and kinetic energy  $\langle T \rangle$

$$\langle T \rangle = -\frac{\langle E \rangle}{2} \text{ where } E_g = \frac{E_0}{1}, E_e = \frac{E_0}{16} \Rightarrow \frac{T_g}{T_e} = \frac{E_g}{E_e} = \frac{16}{1} = 16:1$$

**Note:**

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